

Docket No.: 61352-041

REQUEST FORM FOR CONTINUATION APPLICATION UNDER 35 USC 111(a)

Prior Application: **International Application No. PCT/JP02/13350**
Art Unit: **(Unassigned)**
Examiner: **(Unassigned)**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

15535 U.S. PTO
10/620432
07/17/03

Sir:

This is a Request for filing a continuation application, entitled METHOD OF FABRICATING NITRIDE BASED SEMICONDUCTOR SUBSTRATE AND METHOD OF FABRICATING NITRIDE BASED SEMICONDUCTOR DEVICE, under 35 U.S.C. 111(a) of pending prior International Application No. PCT/JP02/13350, filed on December 20, 2002, entitled METHOD FOR MAKING NITRIDE SEMICONDUCTOR SUBSTRATE AND METHOD FOR MAKING NITRIDE SEMICONDUCTOR DEVICE, by the following named inventor(s):

INVENTOR	RESIDENCE	CITIZENSHIP	POST OFFICE ADDRESS
Hiroyuki FURUYA	Nara-shi, Nara, JAPAN	Japanese	1-6-24-403, Jingu, Nara-shi, Nara 631-0804 JAPAN
Toshiya YOKOGAWA	Nara-shi, Nara, JAPAN	Japanese	5-2-24, Aoyama, Nara-shi, Nara 630-8101 JAPAN
Akihiko ISHIBASHI	Mishima-gun, Osaka, JAPAN	Japanese	2-2220-301, Todaiji, Shimamoto- cho, Mishima-gun, Osaka 618- 0002 JAPAN
Yoshiaki HASEGAWA	Katano-shi, Osaka, JAPAN	Japanese	4-9-401, Ikuno, Katano-shi, Osaka 576-0054 JAPAN

1. ☒ I hereby verify, to the best of my knowledge, that the enclosed copy of this prior application is a true copy of the above-identified prior application.
2. ☒ Preliminary Amendment is enclosed.
- 2a. ☐ An Information Disclosure Statement and PTO1449 Form are submitted herewith.
3. ☐ Cancel claims



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PATENT TRADEMARK OFFICE

4. The filing fee is calculated on the basis of the claims existing in the prior application as amended at 2 above:

	NO. OF CLAIMS		EXTRA CLAIMS	RATE	AMOUNT
Total Claims	22	-20	2	\$18.00 =	\$36.00
Independent Claims	6	-3	3	\$84.00 =	\$252.00
Basic Application Fee					\$750.00
If multiple dependent claims are presented, add \$280.00					\$0.00
Total Application Fee					\$1038.00
Subtract ½ if small entity					\$0.00
Assignment and Recording Fee					\$40.00
TOTAL APPLICATION FEE DUE					\$1078.00
AMOUNT TO BE CHARGED TO DEPOSIT ACCOUNT NO. 500417					\$1078.00


- 4a. ☐ Enclosed is a Verified Statement to establish small entity status under 37 CFR 1.9 and 37 CFR 1.27.
- 4b. ☐ A verified Statement to establish small entity status under 37 CFR 1.9 and 37 CFR 1.27 was filed in prior application and such status is still proper and desired.
5. ☒ The Commissioner is hereby authorized to charge fees under 37 CFR 1.16 and 1.17 which may be required, including any extension of time fees including any extension of time fees to maintain the pendency of the parent application Serial No. ___ or credit any overpayment to Deposit Account No. 500417.
6. ☐ Amend the specification by inserting before the first line the sentence:
7. ☒ Priority of Japanese Application Serial No. 2001-387033 filed on December 20, 2001, in Japan and International Application No. PCT/JP02/13350 filed December 20, 2002 designating the U.S. is claimed under 35 USC 119, 120 and/or 365. A certified copy of the priority document is enclosed.
8. ☒ The prior application is assigned of record to **Matsushita Electric Industrial Co., Ltd.**
Osaka, JAPAN
9. ☐ The power of attorney in the prior application is to:

10. ☒ Also enclosed: 39 pages of specification, claims, and abstract
11 pages of drawings
Declaration and Power of Attorney
Assignment
Form PCT/IB/301, 304, 345
11. ☐ A petition, fee and response has been filed to extend the term in the pending prior application until
12. ☒ Address all future communications to: (May only be completed by applicant, or attorney or agent of record)

McDERMOTT, WILL & EMERY
600 13th Street, N.W.
Washington, DC 20005-3096

Respectfully submitted,

McDERMOTT, WILL & EMERY


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Date: July 17, 2003